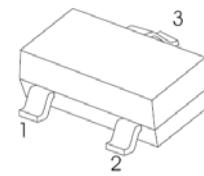


<b>V<sub>DS</sub></b>	<b>-30</b>	<b>V</b>
<b>V<sub>GS Max</sub></b>	<b>± 20</b>	<b>V</b>
<b>R<sub>DS(on) max</sub></b> (@V <sub>GS</sub> = -10V)	<b>165</b>	<b>mΩ</b>
<b>R<sub>DS(on) max</sub></b> (@V <sub>GS</sub> = -4.5V)	<b>270</b>	<b>mΩ</b>

**SOT - 23**

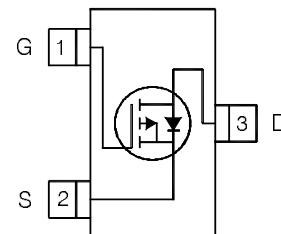
1. GATE  
2. SOURCE  
3. DRAIN

**Features**

- Industry-standard pinout
- Compatible with existing Surface Mount Techniques
- RoHS compliant containing no lead, no bromide and no halogen
- MSL1, Consumer qualification
- 

**Benefits**

- Increased reliability
- Multi-vendor compatibility
- Easier manufacturing
- Environmentally friendly

**Absolute Maximum Ratings**

Symbol	Parameter	Max	Units
V <sub>DS</sub>	Drain-Source Voltage	-30	V
I <sub>D</sub> @ T <sub>A</sub> = 25°C	Continuous Drain Current, V <sub>GS</sub> @ 10V	-2.3	A
I <sub>D</sub> @ T <sub>A</sub> = 70°C	Continuous Drain Current, V <sub>GS</sub> @ 10V	-1.8	
I <sub>DM</sub>	Pulsed Drain Current	-12	
P <sub>D</sub> @ T <sub>A</sub> = 25°C	Maximum Power Dissipation	1.25	W
P <sub>D</sub> @ T <sub>A</sub> = 70°C	Maximum Power Dissipation	0.80	
	Linear Derating Factor	0.01	W/°C
V <sub>GS</sub>	Gate-to-Source Voltage	± 20	V
T <sub>J</sub> , T <sub>STG</sub>	Junction and Storage Temperature Range	-55 to + 150	°C

**Thermal Resistance**

Symbol	Parameter	Typ.	Max.	Units
R <sub>0JA</sub>	Junction-to-Ambient ③	—	100	°C/W
R <sub>0JA</sub>	Junction-to-Ambient (t<10s) ④	—	99	

① Repetitive rating; pulse width limited by max. junction temperature.

② Pulse width ≤ 400μs; duty cycle ≤ 2%.

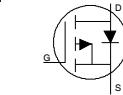
③ Surface mounted on 1 in square Cu board.

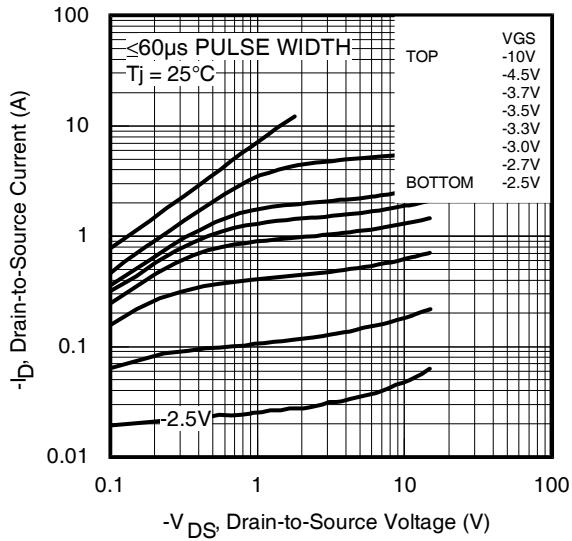
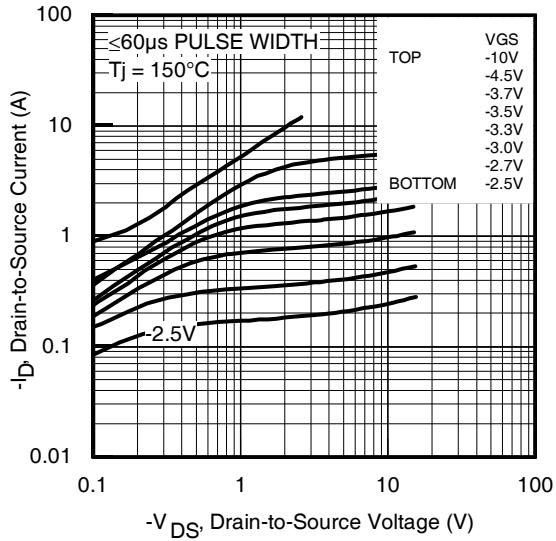
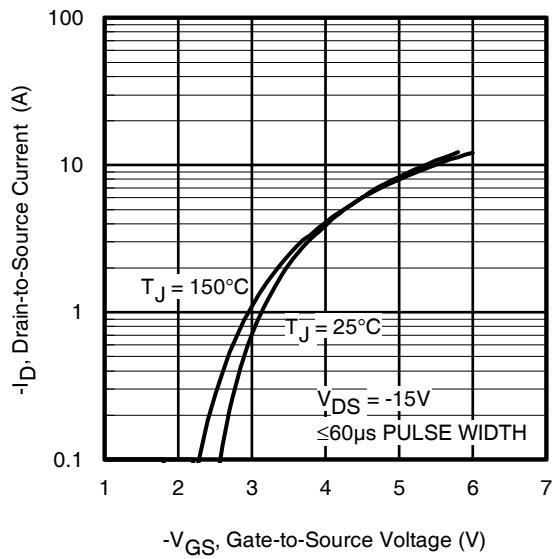
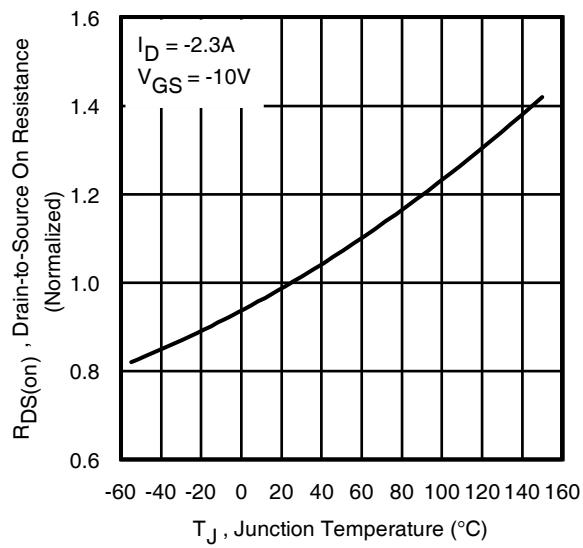
**Electric Characteristics @  $T_J = 25^\circ\text{C}$  (unless otherwise specified)**

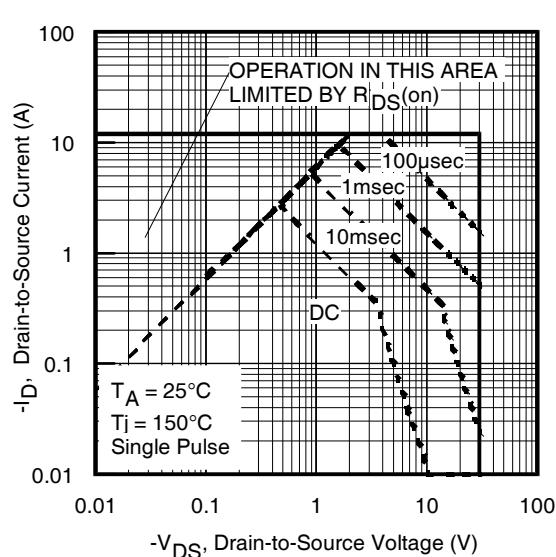
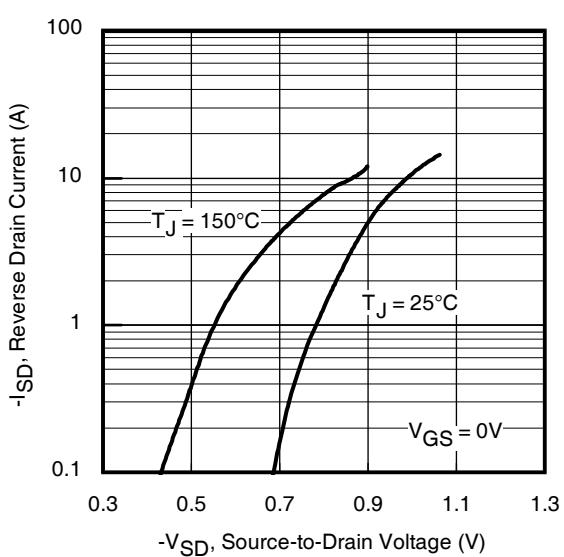
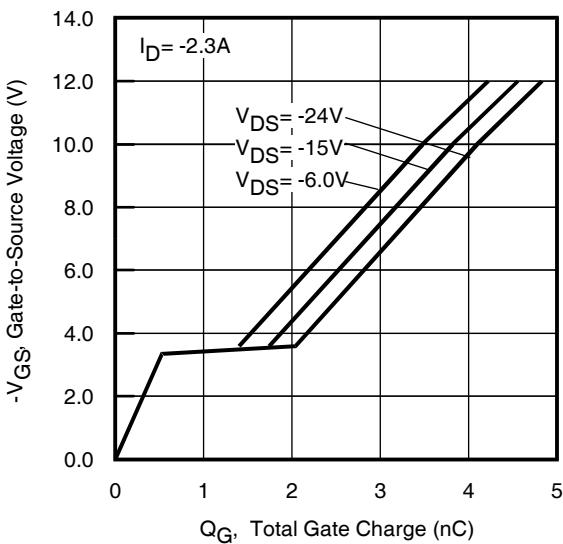
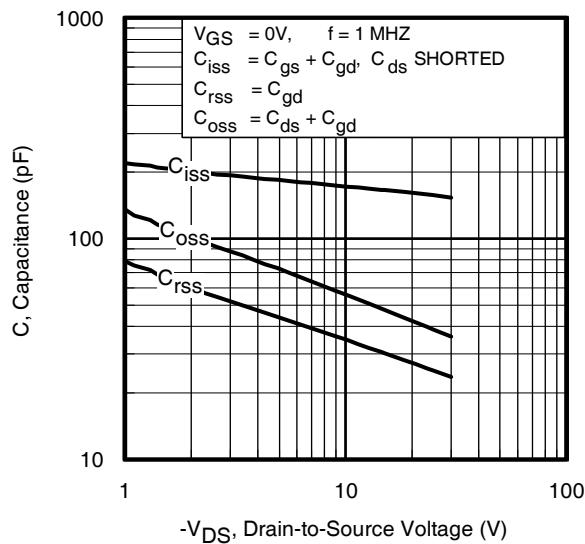
Symbol	Parameter	Min.	Typ.	Max.	Units	Conditions
$V_{(\text{BR})\text{DSS}}$	Drain-to-Source Breakdown Voltage	-30	—	—	V	$V_{GS} = 0V, I_D = -250\mu\text{A}$
$\Delta V_{(\text{BR})\text{DSS}}/\Delta T_J$	Breakdown Voltage Temp. Coefficient	—	-3.7	—	mV/°C	Reference to $25^\circ\text{C}, I_D = -1\text{mA}$
$R_{DS(\text{on})}$	Static Drain-to-Source On-Resistance	—	135	165	$\text{m}\Omega$	$V_{GS} = -10V, I_D = -2.3\text{A}$ ②
		—	220	270		$V_{GS} = -4.5V, I_D = -1.8\text{A}$ ②
$V_{GS(\text{th})}$	Gate Threshold Voltage	-1.3	—	-2.4	V	$V_{DS} = V_{GS}, I_D = -10\mu\text{A}$
$I_{DSS}$	Drain-to-Source Leakage Current	—	—	1.0	$\mu\text{A}$	$V_{DS} = -24V, V_{GS} = 0V$
		—	—	150		$V_{DS} = -24V, V_{GS} = 0V, T_J = 125^\circ\text{C}$
$I_{GSS}$	Gate-to-Source Forward Leakage	—	—	-100	$\text{nA}$	$V_{GS} = -20V$
	Gate-to-Source Reverse Leakage	—	—	100		$V_{GS} = 20V$
$R_G$	Internal Gate Resistance	—	21	—	$\Omega$	
$g_{fs}$	Forward Transconductance	2.3	—	—	S	$V_{DS} = -10V, I_D = -2.3\text{A}$
$Q_g$	Total Gate Charge	—	2.0	—	$\text{nC}$	$I_D = -2.3\text{A}$
$Q_{gs}$	Gate-to-Source Charge	—	0.57	—		$V_{DS} = -15V$
$Q_{gd}$	Gate-to-Drain ("Miller") Charge	—	1.2	—		$V_{GS} = -4.5V$ ②
$t_{d(on)}$	Turn-On Delay Time	—	7.5	—	$\text{ns}$	$V_{DD} = -15V$ ②
$t_r$	Rise Time	—	14	—		$I_D = -1.0\text{A}$
$t_{d(off)}$	Turn-Off Delay Time	—	9.0	—		$R_G = 6.8\Omega$
$t_f$	Fall Time	—	8.6	—		$V_{GS} = -4.5V$
$C_{iss}$	Input Capacitance	—	160	—	$\text{pF}$	$V_{GS} = 0V$
$C_{oss}$	Output Capacitance	—	39	—		$V_{DS} = -25V$
$C_{rss}$	Reverse Transfer Capacitance	—	25	—		$f = 1.0\text{KHz}$

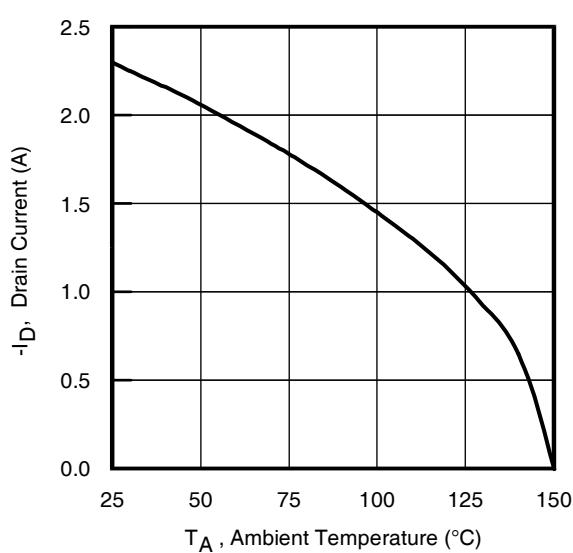
**Source - Drain Ratings and Characteristics**

Symbol	Parameter	Min.	Typ.	Max.	Units	Conditions
$I_S$	Continuous Source Current (Body Diode)	—	—	-1.3	A	MOSFET symbol showing the integral reverse p-n junction diode.
$I_{SM}$	Pulsed Source Current (Body Diode) ①	—	—	-12		
$V_{SD}$	Diode Forward Voltage	—	—	-1.2	V	$T_J = 25^\circ\text{C}, I_S = -1.3\text{A}, V_{GS} = 0V$ ②
$t_{rr}$	Reverse Recovery Time	—	12	18	ns	$T_J = 25^\circ\text{C}, V_R = -24V, I_F = -1.3\text{A}$ $dI/dt = 100\text{A}/\mu\text{s}$ ②
$Q_{rr}$	Reverse Recovery Charge	—	5.3	8.0	nC	

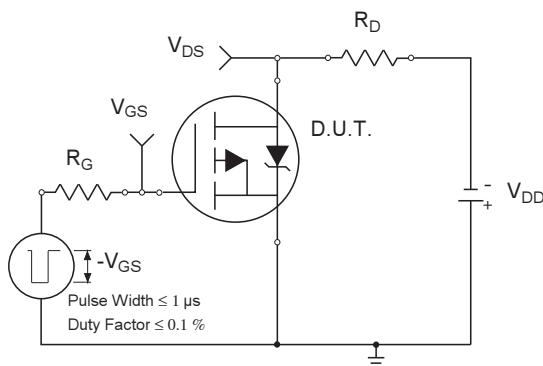


**TYPICAL CHARACTERISTICS** (25 °C, unless otherwise noted)

**Fig 1.** Typical Output Characteristics

**Fig 2.** Typical Output Characteristics

**Fig 3.** Typical Transfer Characteristics

**Fig 4.** Normalized On-Resistance  
vs. Temperature

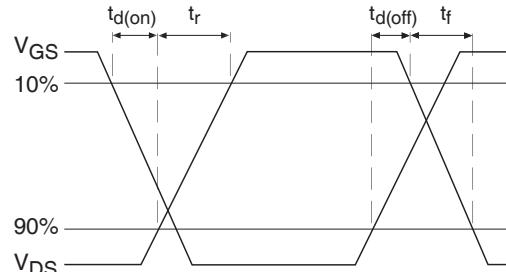
**TYPICAL CHARACTERISTICS** (25 °C, unless otherwise noted)




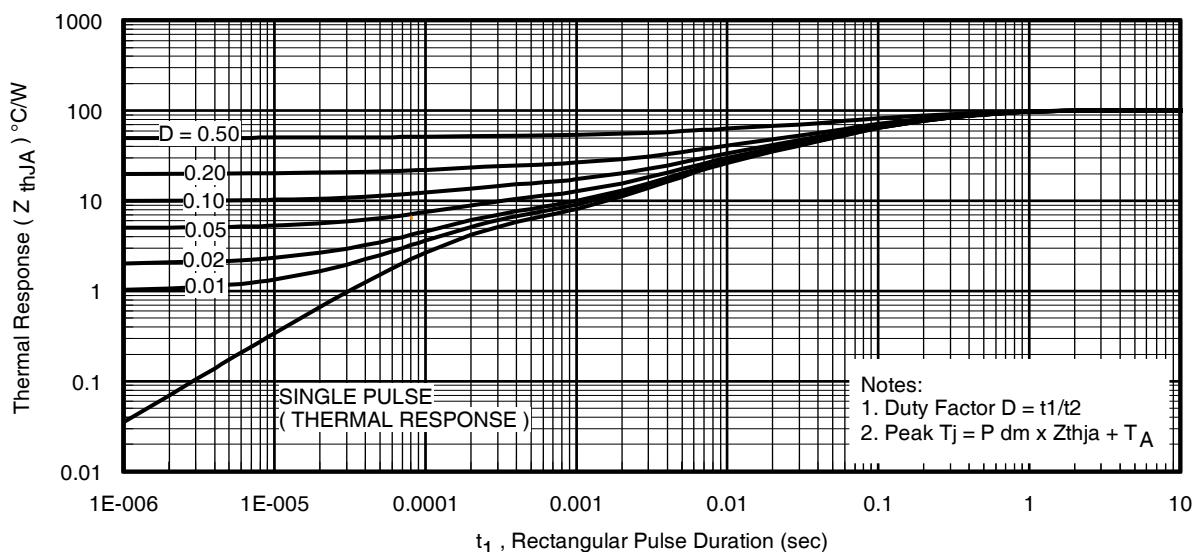
**Fig 9.** Maximum Drain Current vs.  
Ambient Temperature



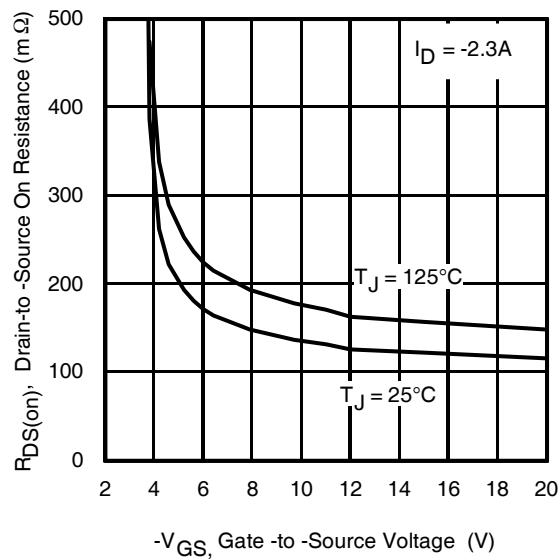
**Fig 10a.** Switching Time Test Circuit



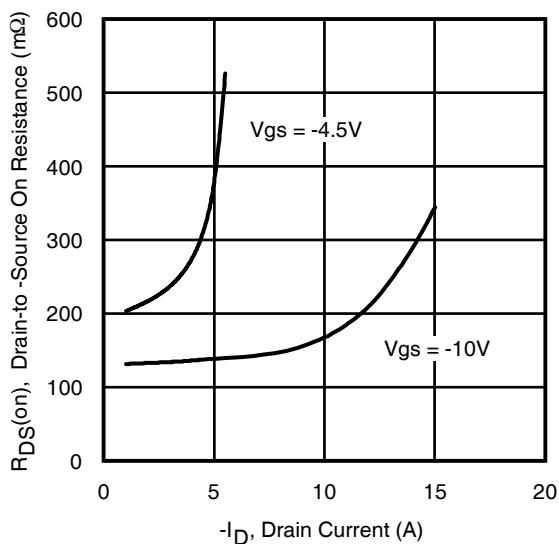
**Fig 10b.** Switching Time Waveforms



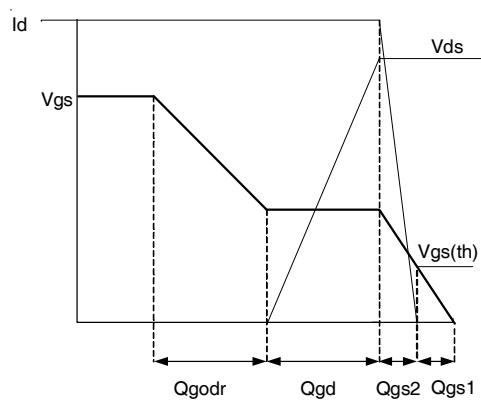
**Fig 11.** Typical Effective Transient Thermal Impedance, Junction-to-Ambient



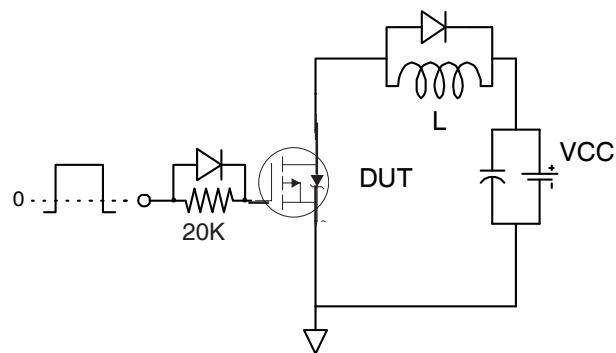
**Fig 12.** Typical On-Resistance vs. Gate Voltage



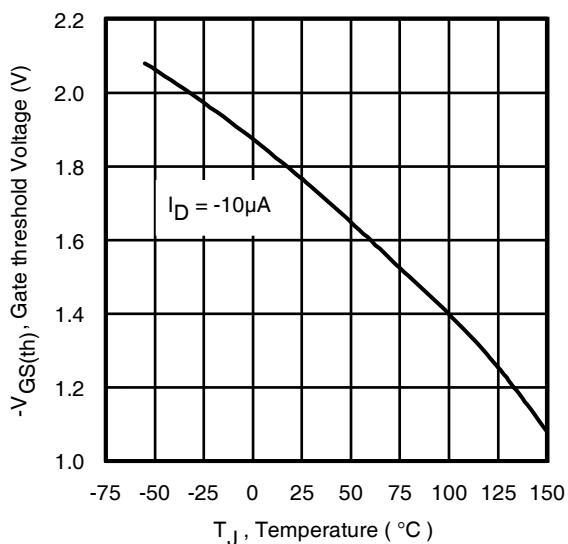
**Fig 13.** Typical On-Resistance vs. Drain Current



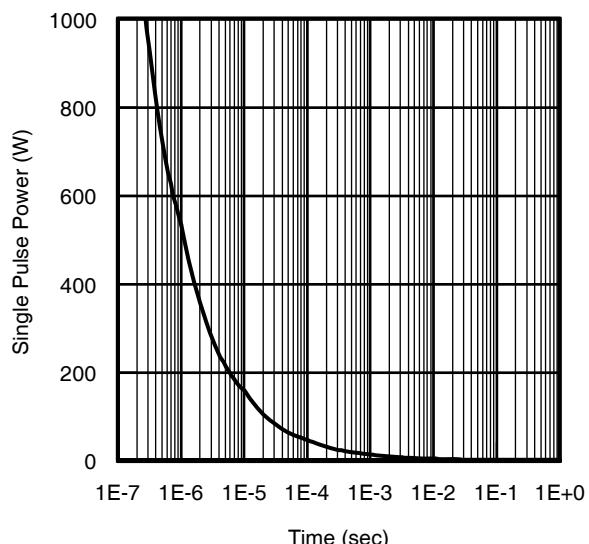
**Fig 14a.** Gate Charge Waveform



**Fig 14b.** Gate Charge Test Circuit

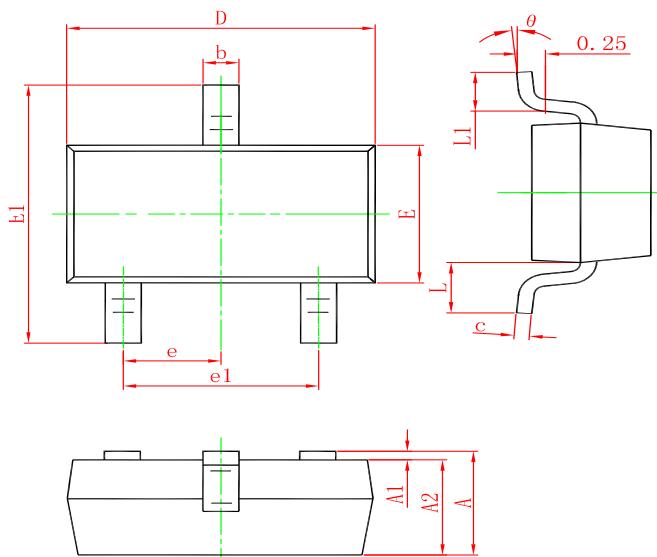


**Fig 15.** Typical Threshold Voltage vs.  
Junction Temperature



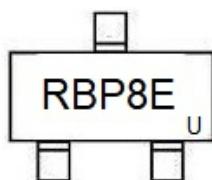
**Fig 16.** Typical Power vs. Time

## SOT-23 PACKAGE OUTLINE DIMENSIONS



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP.		0.037 TYP.	
e1	1.800	2.000	0.071	0.079
L	0.550 REF.		0.022 REF.	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

## Marking



## Ordering information

Order code	Package	Baseqty	Deliverymode
UMW IRLML9303TR	SOT-23	3000	Tape and reel

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